

Water-enriched WO<sub>3</sub> Nanostructures for  
Electrochromic Energy Storage and  
Photovoltaic Cell Integrated Electrochromic System

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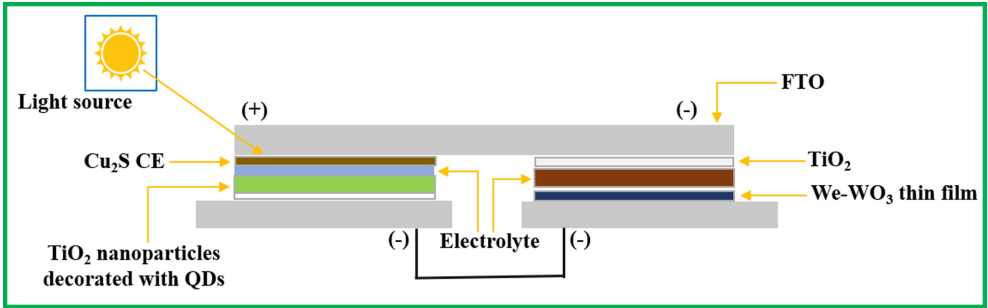


Fig. S1. Schematic arrangement of QDSSC-assisted We-WO<sub>3</sub> integrated device.

Table S1. Resistance parameters and electrochemical active area (EASA) from electrochemical impedance spectroscopy (EIS) analysis

Samples	$R_s$ ( $\Omega$ )	$R_{ct}$ ( $\Omega$ )	EASA ( $\text{cm}^2$ )	$\Delta E$ (V)
WO <sub>3</sub>	8.4	25.3	0.0014	0.30
We-WO <sub>3</sub>	7.5	20.5	0.0021	0.25

Table S2. Electrochromic parameters of ECD-WO<sub>3</sub> and We-WO<sub>3</sub> films measured at 750 nm

Samples	$t_b$ (s)	$t_c$ (s)	$\Delta T$ (%)	CE ( $\text{cm}^2/\text{C}$ )
WO <sub>3</sub>	3.4	5.2	56.7	75.3
We-WO <sub>3</sub>	1.6	3.3	73.6	93.1

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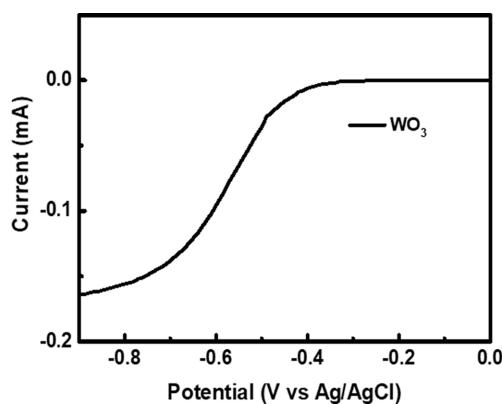


Fig. S2. Linear sweep voltammetry curves of  $\text{WO}_3$ .

An aqueous solution of 0.1 M  $\text{Na}_2\text{WO}_4 \cdot 2\text{H}_2\text{O}$  was prepared and pH-adjusted to 1.0 for use in the LSV measurement of  $\text{WO}_3$  (Fig. S2). Based on the LSV results, a constant potential of  $-0.8$  V is confirmed for fabricating the  $\text{WO}_3$  and We- $\text{WO}_3$  films over the ITO surface.

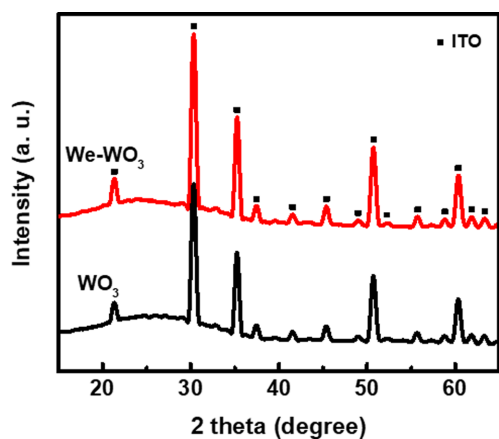


Fig. S3. XRD patterns of  $\text{WO}_3$  and We- $\text{WO}_3$  thin films.

To investigate the crystalline nature of the  $\text{WO}_3$  and We- $\text{WO}_3$  films, XRD measurements were performed, and the results are presented in Fig. S3. No diffraction peaks were observed for either film. The various peaks observed in the figure originate from the ITO surface. This suggests that both fabricated films are amorphous in nature.

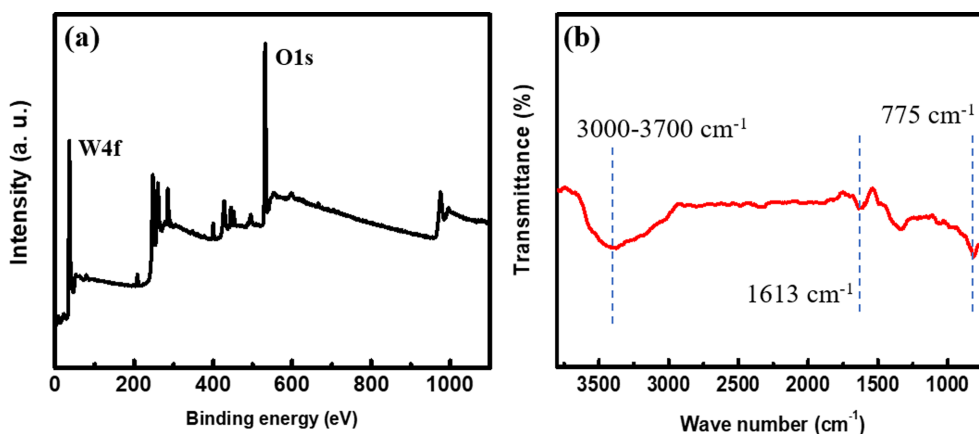


Fig. S4. (a) XPS survey and (b) FTIR spectra of We- $\text{WO}_3$  film.

The XPS survey spectrum of the We- $\text{WO}_3$  film reveals atomic compositions of 17.1% W and 82.9% O (Fig. S4a). To confirm the enhancement of the water content of We- $\text{WO}_3$ , FTIR measurements were performed. This revealed the presence of hydrophilic groups, where a broad band appeared in the wavelength range of 3000–3700 /cm due to the O–H stretching vibration of the adsorbed water, as shown in Fig. S4b. Additionally, the band at 775 /cm is characteristic of W–O bonding.

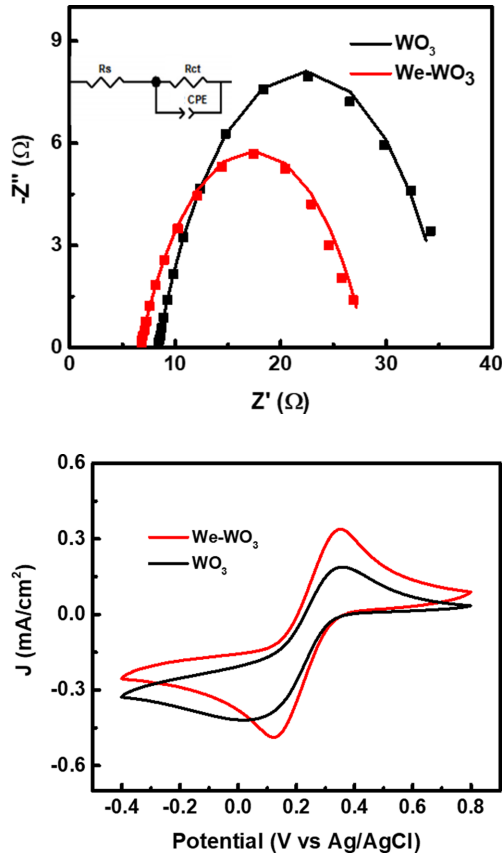


Fig. S5. Impedance measurement for  $\text{WO}_3$  and  $\text{We-WO}_3$  thin films.

The Nyquist plots for both films were obtained using impedance measurements, as shown in Fig. S5. Notably,  $\text{We-WO}_3$  demonstrated the minimum charge-transfer resistance ( $R_{ct}$ ) and series resistance ( $R_s$ ) of 20.5  $\Omega$  and 7.5  $\Omega$ , respectively. On the other hand, the  $\text{WO}_3$  film electrode exhibited an  $R_{ct}$  of 25.3  $\Omega$  and an  $R_s$  of 8.4  $\Omega$ . The results are summarized in Table S1. The overall electrochemical performance of  $\text{We-WO}_3$  was attributed to improved charge transfer. Additionally, the minimal  $R_s$  value could be attributed to the enhanced active surface area resulting from the dispersed and exposed morphologies.

Fig. S6. CV data acquired in 0.1 M  $[\text{Fe}(\text{CN})]^{3-}$  for  $\text{WO}_3$  and  $\text{We-WO}_3$  thin films.

To calculate the electrochemical active surface area (EASA) of both films, CV was performed in 0.1 M  $[\text{Fe}(\text{CN})]^{3-}$ , as shown in Fig. S6. The Randles-Sevcik equation was employed to calculate the EASA.  $\text{We-WO}_3$  exhibited a higher EASA of 0.0021  $\text{cm}^2$ , compared to  $\text{WO}_3$  (0.0014  $\text{cm}^2$ ). In addition,  $\text{We-WO}_3$  also possessed a minimum peak separation ( $\Delta V$ ) between the oxidation and reduction peaks, as seen in the above CV curve. This indicates that the surface of  $\text{We-WO}_3$  is more suitable for the movement of ions during the electrochemical process.

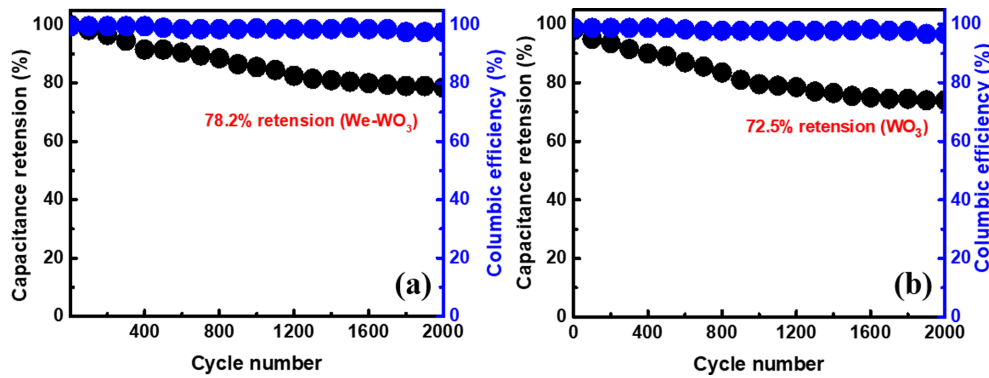


Fig. S7. Cyclic performance and coulombic efficiency of (a)  $\text{We-WO}_3$  and (b)  $\text{WO}_3$  thin films.

The capacitance retention (%) and coulombic efficiencies were measured for the  $\text{We-WO}_3$  and  $\text{WO}_3$  thin film electrodes at a current density of 5  $\text{mA}/\text{cm}^2$  in the potential range of  $-0.9$ – $0.7$  V. Based on the charge/discharge measurements up to 2000 cycles,  $\text{We-WO}_3$  and  $\text{WO}_3$  possess capacitive retentions of 78.2% and 72.5%, respectively. In addition,  $\text{We-WO}_3$  exhibited a coulombic efficiency of  $>95\%$ , suggesting good reversibility.